

FEATURES

- Clock frequency: 133MHz with CAS latency 3
- Burst read / write and burst read / single write capability
- Data input and output masking
- Programmable burst length: 1, 2, 4, 8 and full page
- Programmable burst type: sequential and interleave
- Programmable CAS latency: 3
- Auto refresh and self refresh capability
- 8K refresh per 64ms
- 256 byte serial EEPROM
- LVTTTL-compatible inputs and outputs
- Low active and standby current consumption
- Decoupling capacitors at each memory device
- Single-sided module
- 0.940 inch height
- Gold card edge fingers

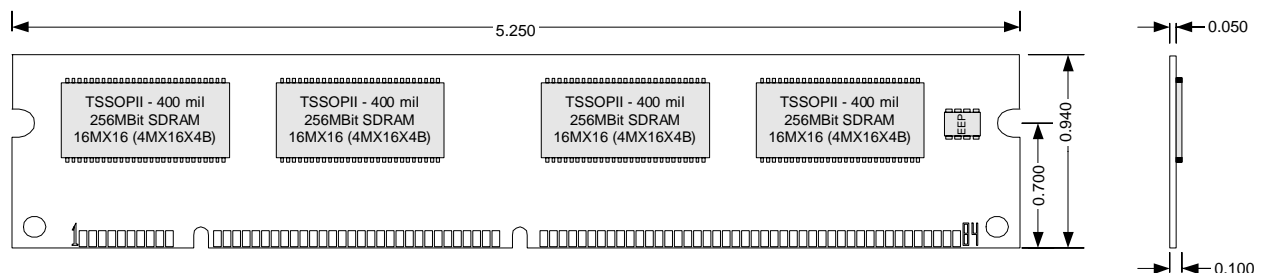
DESCRIPTION

The AVE6416U40A3133E3 is an Unbuffered SDRAM DIMM memory module. This module is based on the INTEL PC133 SDRAM DIMM Version 1.0. A 256 byte serial EEPROM on board can be used to store module information such as timing, configuration, density, etc...

The AVE6416U40A3133E3 memory module is 128MByte and organized as 16MX64 array using (4) 16MX16 (4 internal banks) SDRAMs in TSSOP II packages.

All memory modules are fabricated using the latest technology design, four-layer printed circuit board substrate construction with low ESR decoupling capacitors on-board for high reliability and low noise.

PHYSICAL DIMENSIONS



Avant Ordering Guides

| INVENTORY | MOD. TYPE | ORG. | DENSITY | PARITY | TYPE | VOLT. | FEATURE | SPEED | MODE | REV |
|------------|------------------|--------|----------|--------------|-----------------|--------|----------------------|--------|--------|-------|
| AV = AVANT | E = 168-PIN DIMM | 64=X64 | 16 = 16M | U=UNBUFFERED | 40=4Mx16x4 (8K) | A=3.3V | 3=CAS LATENCY 3 ONLY | 133MHz | E=SYNC | REV=3 |

Other options may be available. Call for specific part number information on options not listed.



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